

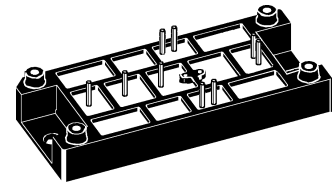
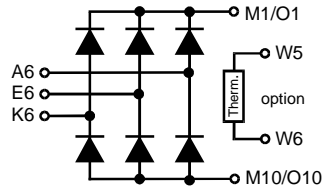
Three Phase Rectifier Bridge

$$I_{dAVM} = 121/157 \text{ A}$$

$$V_{RRM} = 1200-1600 \text{ V}$$

Preliminary Data

V_{RRM}	Type	V_{RRM}	Type
V	V		
1200	VUO 120-12 NO1	1600	VUO 120-16 NO1
1200	VUO 155-12 NO1	1600	VUO 155-16 NO1



Symbol	Test Conditions	Maximum Ratings		
		VUO 120	VUO155	
V_{RRM}		1200/1600	1200/1600	V
I_{dAVM}	$T_C = 75^\circ\text{C}$, sinusoidal 120°	121	157	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	650	850	A
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	580	760	A
I^2t	$T_{VJ} = 45^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	2110	3610	A
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	1680	2880	A
P_{tot}	$T_C = 25^\circ\text{C}$ per diode	150	190	W
T_{VJ}		-40...+150		°C
T_{VJM}		150		°C
T_{stg}		-40...+125		°C
V_{ISOL}	50/60 Hz $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$	3000	V~
		$t = 1 \text{ s}$	3600	V~
M_d	Mounting torque (M5) (10-32 unf)		2-2.5	Nm
			18-22	lb.in.
d_s	Creep distance on surface		12.7	mm
d_A	Strike distance in air		9.4	mm
a	Maximum allowable acceleration		50	m/s ²
Weight	typ.		80	g

Features

- Soldering connections for PCB mounting
- Isolation voltage 3600 V~
- Convenient package outline
- UL registered E 72873
- Case and potting UL94 V-0

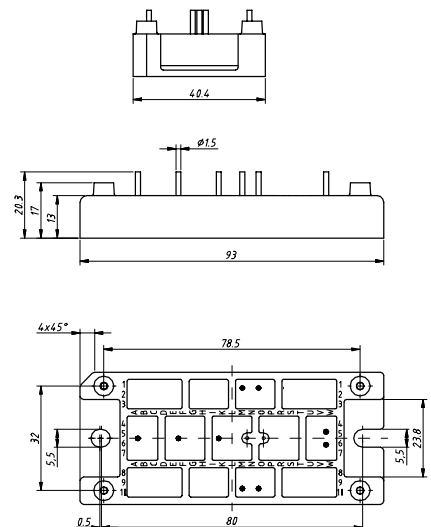
Applications

- Input Rectifier for Drive Inverters

Advantages

- Easy to mount with two screws
- Suitable for wave soldering
- High temperature and power cycling capability

Dimensions in mm (1 mm = 0.0394")



Symbol	Test Conditions	Characteristic Values ($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
I_R	$V_R = V_{RRM}$, $T_{VJ} = 25^\circ\text{C}$			0.3 mA
	$V_R = V_{RRM}$, $T_{VJ} = 150^\circ\text{C}$			5 mA
V_F	$I_F = 150 \text{ A}$, $T_{VJ} = 25^\circ\text{C}$	VUO 120		1.59 V
		VUO 155		1.49 V
V_{F0}	For power-loss calculations only	VUO 120		0.80 V
		VUO 155		0.75 V
r_T	$T_{VJ} = 150^\circ\text{C}$	VUO 120		6.1 mΩ
		VUO 155		4.6 mΩ
R_{thJC}	per diode	VUO 120		1.0 K/W
		VUO 155		0.8 K/W
R_{thJH}		VUO 120		1.3 K/W
		VUO 155		1.1 K/W
R_{25} (option)	Siemens S 891/2,2/+9			2.2 kΩ